

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Patent No. ....7,141,472 B2  
Patent Issue Date ..... November 28, 2006  
Application Serial No. .... 10/611,602  
Filing Date ..... June 30, 2003  
Assignee ..... Micron Technology, Inc.  
Inventorship ..... Hermes  
Attorney's Docket No. ....MI22-2341  
Title: Semiconductor Processing Methods of Forming Dynamic Random Access  
Memory (DRAM) Circuitry

**REQUEST FOR CERTIFICATE OF CORRECTION OF PATENT**  
**FOR PTO MISTAKE (37 C.F.R. 1.322(a))**

To: Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450  
ATTN: Decision and Certificate of Correction  
Branch of the Patent Issue Division  
  
From: Jennifer J. Taylor, Ph.D. (Tel. 509-624-4276; Fax 509-838-3424)  
Wells St. John P.S.  
601 W. First Avenue, Suite 1300  
Spokane, WA 99201-3828

Sir:

It is hereby requested that a Certificate of Correction be issued with respect to Patent No. 7,141,472 B2, granted November 28, 2006, in accordance with the Certificate of Correction form attached hereto.

The errors listed on the Certificate of Correction form were apparently incurred through the fault of the PTO as will be disclosed by the records of files in the Office.

Since this Certificate of Correction is being requested due to PTO errors, it is believed that no fee is due. However, in the event that a fee is required for issuance of this Certificate of Correction, please charge the fee specified under

37 C.F.R. § 1.20(a) to Deposit Account No. 23-0925. Please credit Deposit Account No. 23-0925 with any overpayment of the above fee.

Attached hereto is Form PTO-1050 which is suitable for printing.

Dated:

July 3 2007

Respectfully submitted,

By:

Jennifer J. Taylor  
Jennifer J. Taylor, Ph.D.  
Reg. No. 48,711

UNITED STATES PATENT AND TRADEMARK OFFICE

**CERTIFICATE OF CORRECTION**

PATENT NO. : 7,141,472 B2

DATED : November 28, 2006

INVENTOR(S) : Hermes

It is certified that errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 2, Line 34 – Replace “subsequent; to” with --subsequent to--.

Column 4, Line 31 – Replace “common, etch” with --common etch--.

Column 4, Line 37 – Replace “Accordingly;” with --Accordingly,--.

Column 5, Line 31 – Replace “under-and” with --under and--.

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1 of 1

**Mailing Address of Sender:**

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